Low-power dual function gate Rev. 11 — 22 July 2019

1. General description

The 74AUP1G885 provides two functions in one device. The output state of the outputs (1Y, 2Y) is determined by the inputs (A, B and C). The output 1Y provides the Boolean function: $1Y = A \times C$. The output 2Y provides the Boolean function: $2Y = \overline{A} \times B + A \times \overline{C}$.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

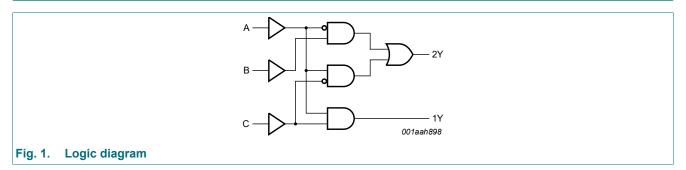
Type number	Package									
	Temperature range	Name	Description	Version						
74AUP1G885DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1						
74AUP1G885GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1						
74AUP1G885GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089						
74AUP1G885GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116						
74AUP1G885GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203						

4. Marking

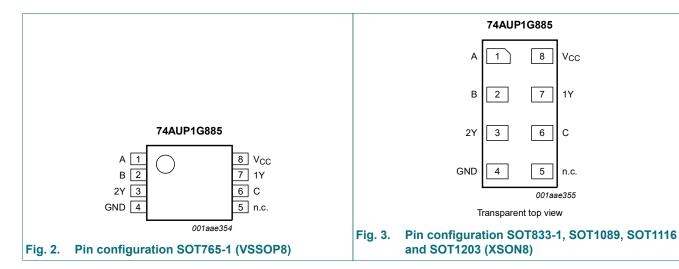
Table 2. Marking codes							
Type number	Marking code [1]						
74AUP1G885DC	pS8						
74AUP1G885GT	pS8						
74AUP1G885GF	58						
74AUP1G885GN	58						
74AUP1G885GS	58						

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description									
Symbol	Pin	Description							
A, B, C	1, 2, 6	data input							
GND	4	ground (0 V)							
n.c.	5	not connected							
1Y, 2Y	7, 3	data output							
V _{CC}	8	supply voltage							

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input		Output		
Α	В	С	1Y	2Y
L	L	L	L	L
Н	L	L	L	Н
L	Н	L	L	Н
Н	Н	L	L	Н
L	L	Н	L	L
Н	L	Н	Н	L
L	Н	Н	L	Н
Н	Н	Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT765-1 (VSSOP8) packages: P_{tot} derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) packages: P_{tot} derates linearly with 3.1 mW/K above 68 °C.

For SOT1089 (XSON8) packages: P_{tot} derates linearly with 4.0 mW/K above 88 °C.

For SOT1116 (XSON8) packages: P_{tot} derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) packages: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C	·	1	1		1
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	V _I = V _{IH} or V _{IL}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.6	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.3	-	pF

Low-power dual function gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +85 °C	·		1		
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	V _I = V _{IH} or V _{IL}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1	I] -	-	50	μA
						1

Low-power dual function gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C					
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.75V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	V _I = V _{IH} or V _{IL}				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	$V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 5.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Мах	Min	Мах	Min	Max	1
C _L = 5 p	F									
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 4</u> [2]								
	delay	V _{CC} = 0.8 V	-	17.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.1	5.2	9.7	0.9	12.8	0.9	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.2	3.7	5.9	1.0	7.8	1.0	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.1	3.0	4.8	0.9	6.2	0.9	6.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.4	3.6	1.0	4.1	1.0	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.1	2.1	3.1	1.0	3.6	1.0	4.1	ns
		A, B to 2Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	21.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.7	6.0	12.7	1.4	12.8	1.4	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.7	4.2	7.2	1.4	7.8	1.4	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.4	3.3	5.8	1.2	6.5	1.2	7.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.2	2.6	4.1	1.0	4.7	1.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.1	2.3	3.5	0.9	3.8	0.9	4.2	ns
C _L = 10	pF									
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 4</u> [2]								
	delay	V _{CC} = 0.8 V	-	20.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.2	6.1	11.4	1.2	14.6	1.2	16.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.4	4.3	7.2	1.2	8.7	1.2	9.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.4	3.6	5.7	1.3	6.8	1.3	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.9	4.2	1.2	4.8	1.2	5.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.7	3.9	1.3	4.1	1.3	4.6	ns
		A, B to 2Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	25.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.8	6.9	14.4	1.7	14.6	1.7	16.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.9	4.8	8.5	1.5	9.1	1.5	10.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.2	1.7	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	3.1	4.7	1.3	5.4	1.3	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.8	4.3	1.3	4.6	1.3	5.1	ns

Low-power dual function gate

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Мах	Min	Max	Min	Max	
C _L = 15	pF									
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 4</u> [2]								
	delay	V _{CC} = 0.8 V	-	24.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.3	6.9	13.0	1.2	16.2	1.2	17.9	ns
		V _{CC} = 1.4 V to 1.6 V	1.7	4.9	8.0	1.4	9.7	1.4	10.8	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	4.1	6.4	1.4	7.6	1.4	8.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.4	5.0	1.6	5.4	1.6	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.1	4.4	1.6	4.7	1.6	5.3	ns
		A, B to 2Y; see <u>Fig. 4</u> [2]								
		V _{CC} = 0.8 V	-	28.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.1	7.7	16.0	1.9	16.3	1.9	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	5.4	9.4	2.4	10.3	2.4	11.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	4.4	7.4	1.8	8.2	1.8	9.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.6	5.5	1.6	6.0	1.6	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.3	4.8	1.5	5.2	1.5	5.8	ns
C _L = 30	pF									
t _{pd}	propagation delay	A, C to 1Y; see <u>Fig. 4</u> [2]								
		V _{CC} = 0.8 V	-	34.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	9.2	17.7	2.3	20.9	2.3	23.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	6.5	10.6	2.5	12.2	2.5	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	5.4	8.5	2.4	9.4	2.4	10.4	ns
		V_{CC} = 2.3 V to 2.7 V	2.6	4.5	6.4	2.4	7.0	2.4	7.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	4.2	5.7	2.3	6.6	2.3	7.3	ns
		A, B to 2Y; see Fig. 4 [2]								
		V _{CC} = 0.8 V	-	38.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	10.0	20.5	2.6	21.5	2.6	23.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	6.9	11.9	2.6	13.2	2.6	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	5.7	9.5	2.7	10.5	2.7	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	4.7	6.9	2.5	7.6	2.5	8.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.4	6.1	2.4	7.1	2.4	7.9	ns
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF		·						
C _{PD}	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{\text{CC}}$ [3]								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
	supuonanoo	V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.1	-	-	-	-	-	pF

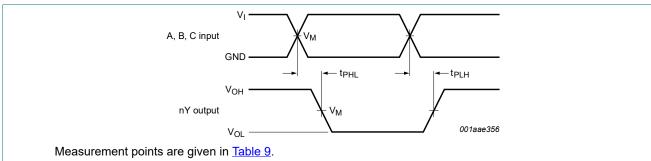
[1] All typical values are measured at nominal $V_{\mbox{\scriptsize CC}}.$

[2] [3]

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Low-power dual function gate



11.1. Waveforms and test circuit

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. The data input (A, B, C) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input					
V _{CC}	V _M	V_M V_l $t_r = t_f$					
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns			

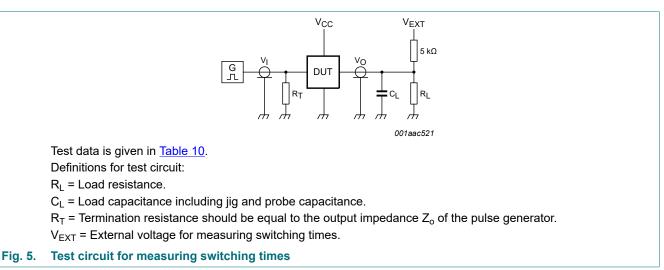


Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$. For measuring propagation delays, set-up and hold times and pulse width $R_L = 1 M\Omega$.

Low-power dual function gate

12. Package outline

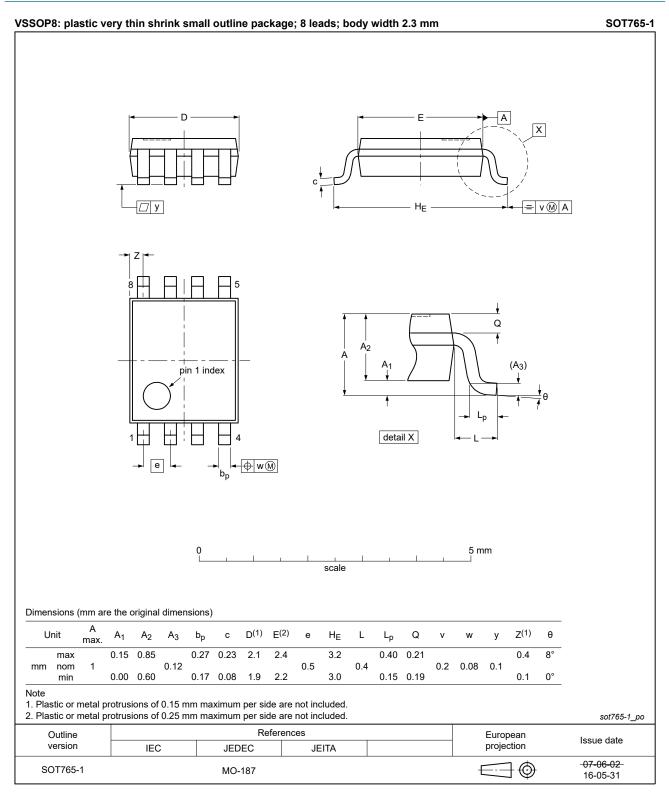


Fig. 6. Package outline SOT765-1 (VSSOP8)

74AUP1G885

Low-power dual function gate

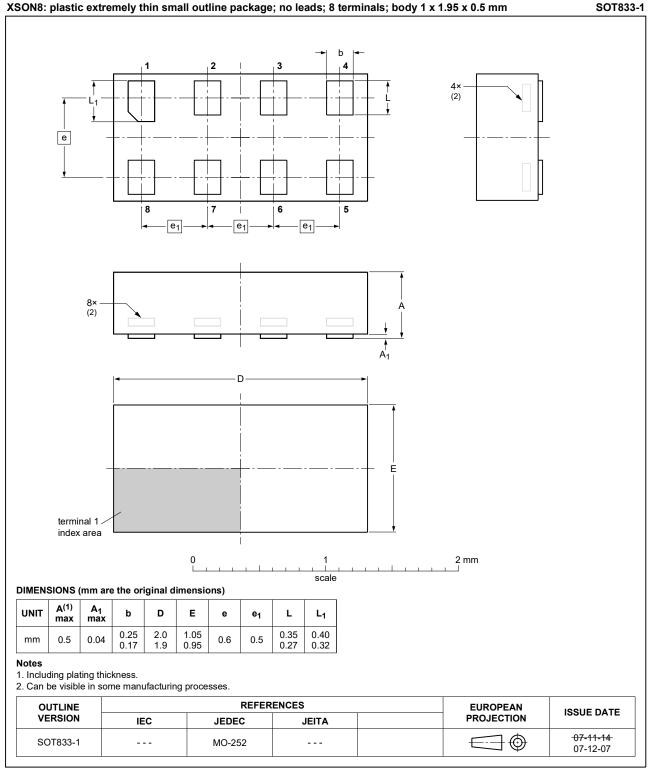
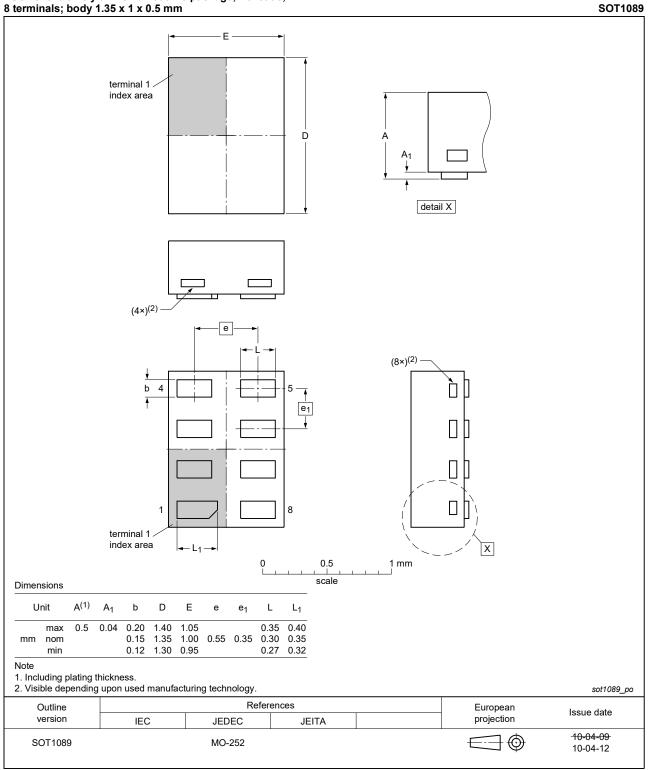


Fig. 7. Package outline SOT833-1 (XSON8)

Low-power dual function gate

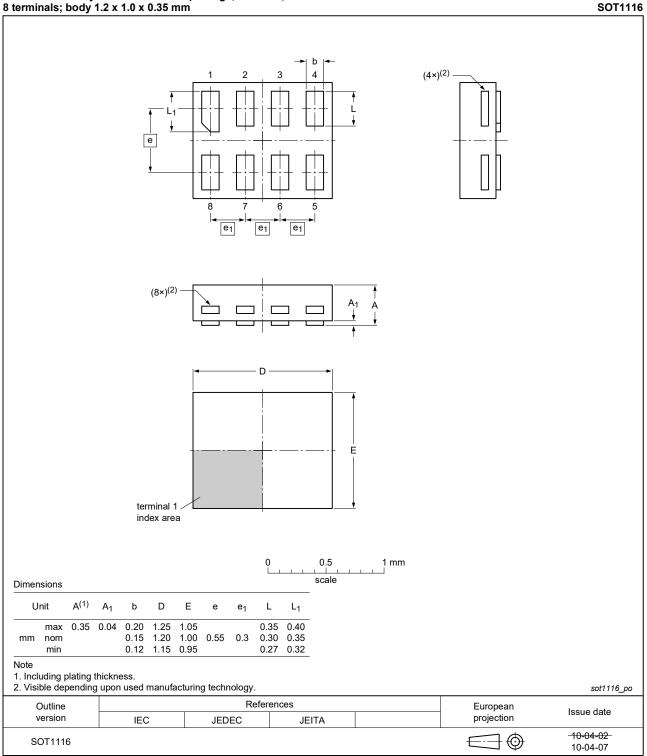


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Package outline SOT1089 (XSON8) Fig. 8.

Low-power dual function gate

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





Low-power dual function gate

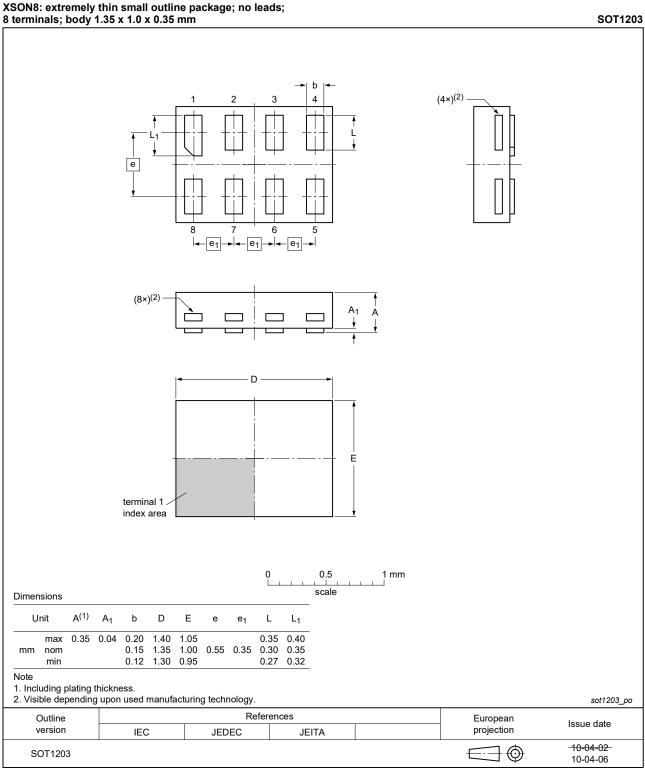


Fig. 10. Package outline SOT1203 (XSON8)

13. Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
MM	Machine Model			

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G885 v.11	20190722	Product data sheet	-	74AUP1G885 v.10
Modifications:	••	per 74AUP1G885GM (SO Table 8 Dynamic character	,	
74AUP1G885 v.10	20190314	Product data sheet	-	74AUP1G885 v.9
Modifications:	of Nexperia • Legal texts • Type numb • Package o		e new company nam [996-2) removed. (VSSOP8) updated.	nply with the identity guidelines e where appropriate.
74AUP1G885 v.9	20130131	Product data sheet	-	74AUP1G885 v.8
Modifications:	For type nu	umber 74AUP1G885GD X	SON8U has change	d to XSON8.
74AUP1G885 v.8	20120608	Product data sheet	-	74AUP1G885 v.7
74AUP1G885 v.7	20111129	Product data sheet	-	74AUP1G885 v.6
74AUP1G885 v.6	20101021	Product data sheet	-	74AUP1G885 v.5
74AUP1G885 v.5	20090626	Product data sheet	-	74AUP1G885 v.4
74AUP1G885 v.4	20090401	Product data sheet	-	74AUP1G885 v.3
74AUP1G885 v.3	20080328	Product data sheet	-	74AUP1G885 v.2
74AUP1G885 v.2	20070710	Product data sheet	-	74AUP1G885 v.1
74AUP1G885 v.1	20061201	Product data sheet	-	-

Low-power dual function gate

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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